

Rev.E Mar.-2016

KF 50) CD

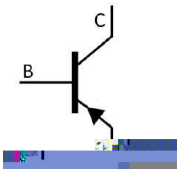
GE G

Silicon PNP transistor in a TO-92LM Plastic Package.

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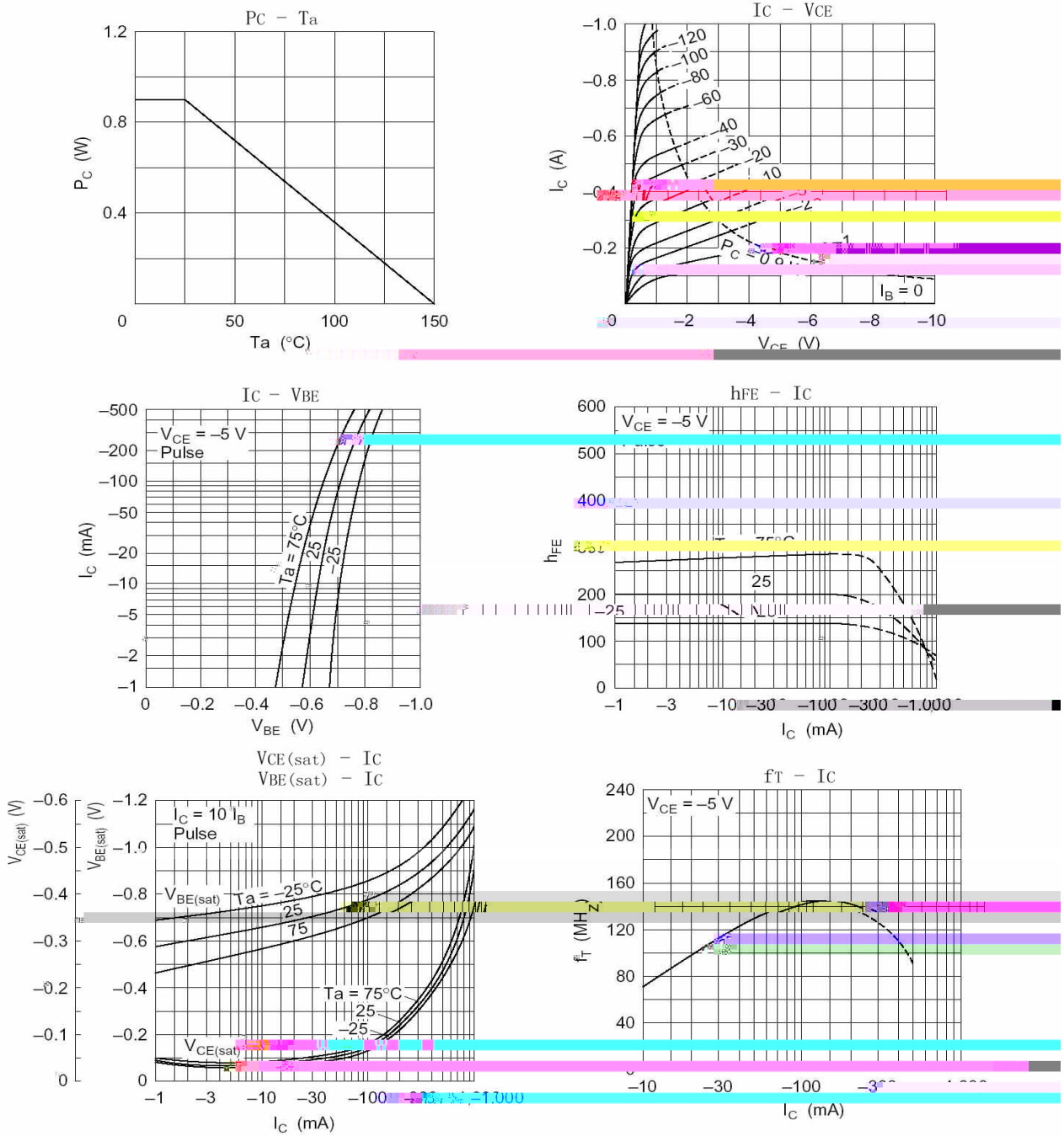
Complementary pair with 2SD667(A).

Low frequency power amplifier.



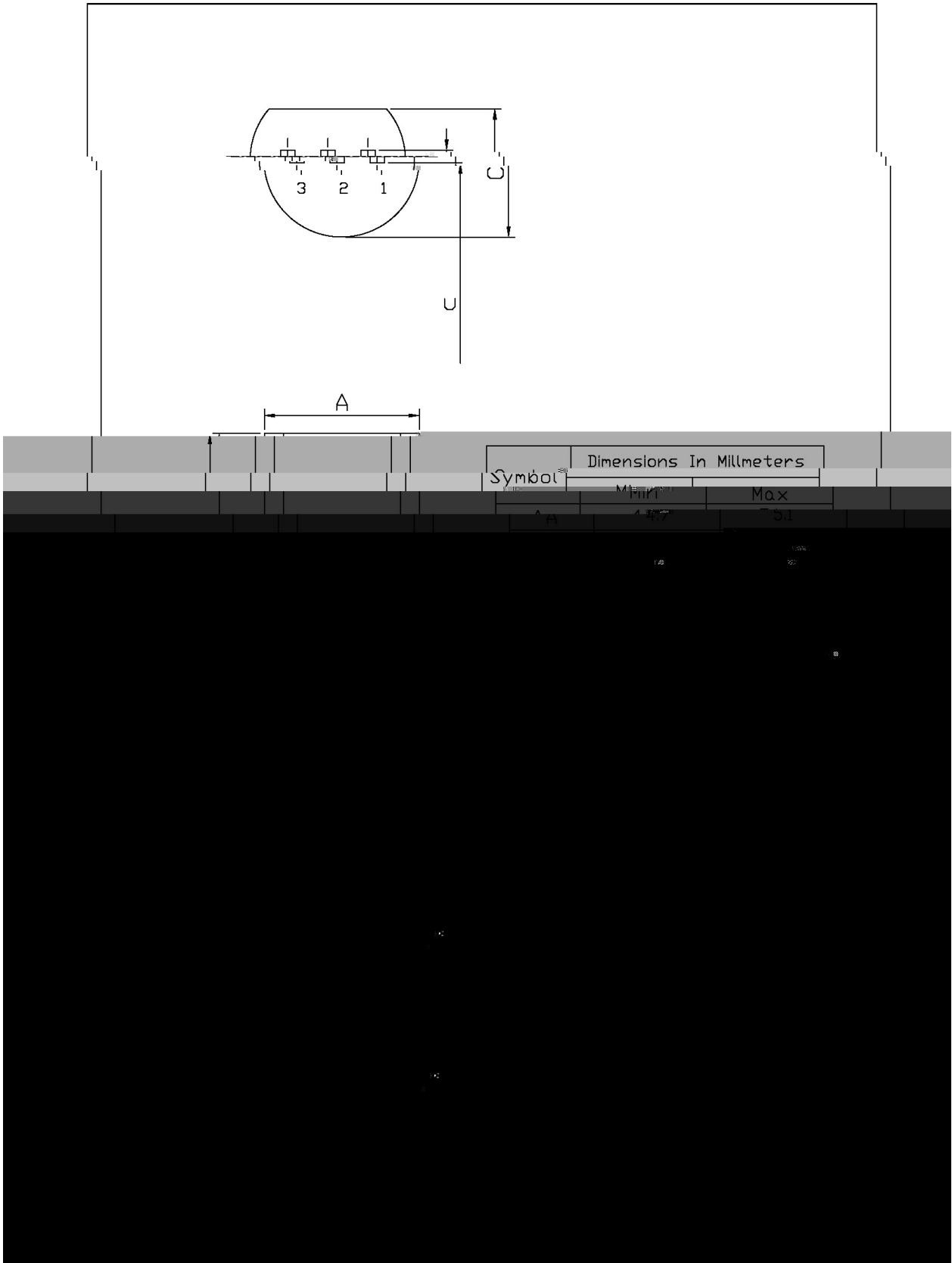
PIN 1 Base PIN 2 Collector PIN 3 Emitter

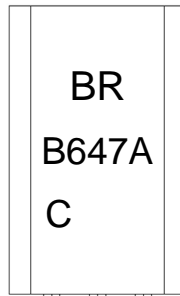
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-120	V
Collector to Emitter Voltage	V_{CEO}	2SB647	-80
		2SB647A	-100
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current (DC)	I_C	-1.0	A
Collector Current(Pulse)	I_{CP}	-2.0	A
Collector Power Dissipation	P_C	900	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T		



TO-92LM

Unit: mm





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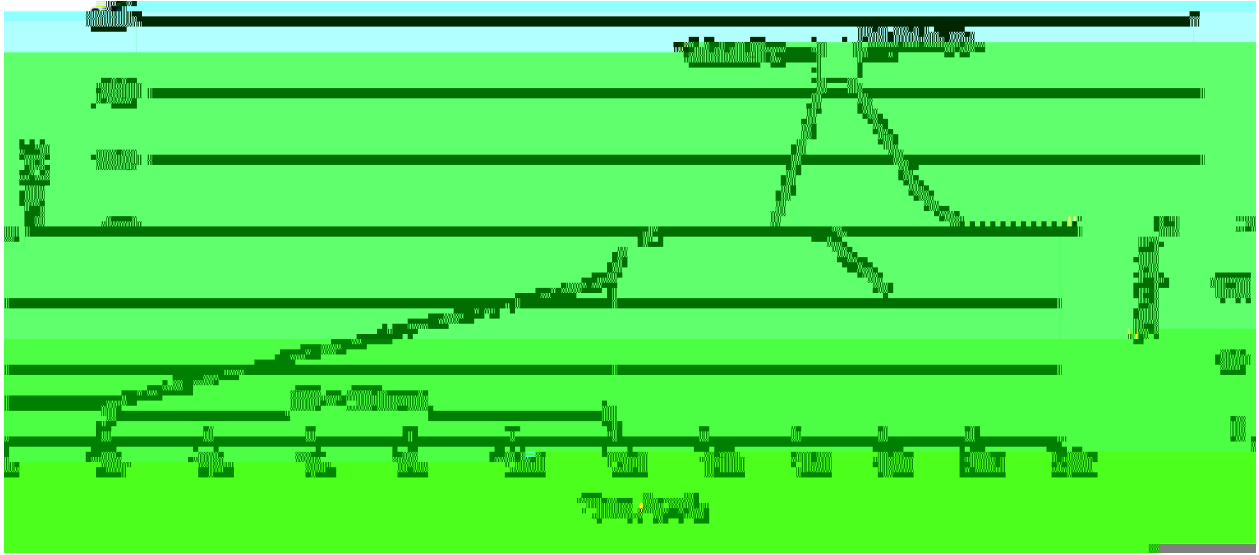
Note:

BR: Company Code.

B647A: Product Type.

C: h_{FE} Classifications Symbol

****: Lot No. Code,code change with Lot No.



1 25 150 60 90sec;

Note:

1.Preheating:25~150